

1. 4MHz Thin Package Current-Mode Step-Up DC/DC Converter

FEATURES

- Fixed Frequency 1.4MHz Current-Mode PWM Operation.
- Adjustable Output Voltage up to 30V.
- Guaranteed 13V/ 200mA Output with 5V Input.
- 2.5V to 10V Input Range.
- Maximum 0.1µA Shutdown Current.
- Programmable Soft-Start.
- Tiny Inductor and Capacitors are allowed.
- Space-Saving SOT-23-6 and TSOT-23-6 Package.

APPLICATIONS

- · White LED Backlight.
- · OLED Driver.
- LCD Bias

DESCRIPTION

AlC1896 is a current-mode pulse-width modulation (PWM), step-up DC/DC Converter. The built-in high voltage N-channel MOSFET allows AlC1896 for step-up applications with up to 30V output voltage, as well as for Single Ended Primary Inductance Converter (SEPIC) and other low-side switching DC/DC converter.

The high switching frequency (1.4MHz) allows the use of small external components. The Soft-Start function is programmable with an external capacitor, which sets the input current ramp rate.

The AIC1896 is available in a space-saving SOT-23-6 and TSOT-23-6 package.

■ TYPICAL APPLICATION CIRCUIT

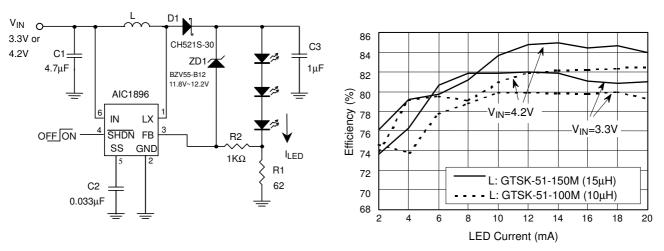


Fig. 1 Li-Ion Powered Driver for three white LEDs



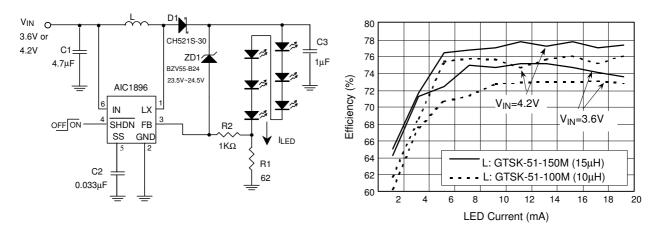
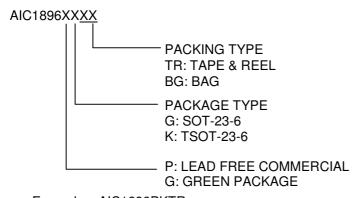


Fig. 2 Li-Ion Powered Driver for six white LEDs

ORDERING INFORMATION



Example: AIC1896PKTR

ightarrow in Lead Free TSOT-23-6 Package & Tape

& Reel Packing Type

AIC1896PGTR

ightarrow in Lead Free SOT-23-6 Package & Tape

& Reel Packing Type

TSOT-23-6 Marking

| Part No. | Marking |
|-----------|---------|
| AIC1896PK | 896PK |
| AIC1896GK | 896GK |

SOT-23-6 Marking

| Part No. | Marking |
|-----------|---------|
| AIC1896PG | 1896P |
| AIC1896GG | 1896G |

| PIN CONFIGURATION | | |
|--|----------------------------------|--|
| SOT-23-6 / TSOT FRONT VIEW 1: LX 2: GND 3: FB 4: SHDN 5: SS 6: IN | T-23-6 6 5 4 1896/1896P 1 2 3 | |
| Note: Pin1 is determined by orienting the package marking as shown. | | |

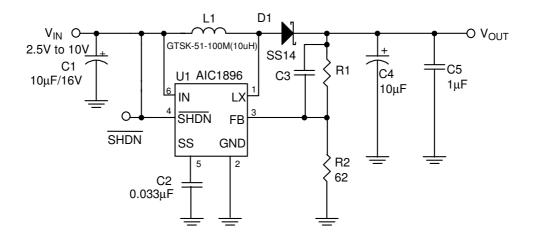


■ ABSOLUTE MAXIMUM RATINGS

| -0.3V to +33V |
|-----------------|
| -0.3V to +6V |
| -0.3V to +11V |
| -0.3V to +6V |
| 0.6A |
| 727mW |
| -40 °C to 85 °C |
| 125℃ |
| -65°C to 150°C |
| 260℃ |
| |

Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

TEST CIRCUIT





■ ELECTRICAL CHARACTERISTICS

 $(V_{IN}=V \overline{\text{SHDN}} = 3V, FB=GND, SS=Open, T_A=25°C, unless otherwise specified) (Note 1)$

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------------------------|----------------------|--|-------|------|-------|-------|
| Input Supply Range | V _{IN} | | 2.5 | | 10 | ٧ |
| Output Voltage Adjust Range | V _{OUT} | | | | 30 | ٧ |
| V _{IN} Undervoltage Lockout | UVLO | V _{IN} rising, 50mV hysteresis | | 2.2 | | V |
| Quiescent Current | I _{IN} | V _{FB} = 1.3V, not switching | | 0.1 | 0.2 | mA |
| | | V _{FB} = 1.0V, switching | | 1 | 5 | |
| Chutdown Cunnly Current | | $V \overline{SHDN} = 0, T_A = +25^{\circ}C$ | | 0.01 | 0.5 | μΑ |
| Shutdown Supply Current | | VSHDN = 0 | | 0.01 | 10 | μΑ |
| ERROR AMPLIFIER | | | | | | |
| Feedback Regulation Set Point | V_{FB} | | 1.205 | 1.23 | 1.255 | V |
| FB Input Bias Current | I _{FB} | V _{FB} = 1.24V | | 21 | 80 | nA |
| Line Regulation | | $2.6V < V_{IN} < 5.5V$ | | 0.05 | 0.20 | %/V |
| OSCILLATOR | | | | | | |
| Frequency | fosc | | 1000 | 1400 | 1800 | KHz |
| Maximum Duty Cycle | DC | | 82 | 86 | | % |
| POWER SWITCH | | | | | | |
| Steady State Output Current | lo | Refer to Fig. 13 | | | | Α |
| On-Resistance | R _{DS(ON)} | Vin = 5V | | 1 | 1.4 | Ω |
| Leakage Current | I _{LX(OFF)} | $V_{LX} = 30V, T_A = +25^{\circ}C$ | | 0.1 | 1 | |
| | | $V_{LX} = 30V$ | | | 10 | μΑ |
| SOFT-START | | | | | | |
| Reset Switch Resistance | | Guaranteed By Design | | | 100 | Ω |
| Charge Current | | V _{SS} = 1.2V | 1.5 | 4 | 7.0 | μΑ |
| CONTROL INPUT | | | | | | |
| Input Low Voltage | V _{IL} | $V \overline{SHDN}$, $V_{IN} = 2.5V$ to 10V | | | 0.3 | V |
| Input High Voltage | V _{IH} | $V \overline{SHDN}$, $V_{IN} = 2.5V$ to 10V | 1.0 | | | V |
| CLIDN leavet Course | ISHDN | VSHDN = 1.8V | | 25 | 50 | |
| SHDN Input Current | | VSHDN = 0 | | 0.01 | 0.1 | μΑ |

Note 1: Specifications are production tested at T_A=25°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with Statistical Quality Controls (SQC).



■ TYPICAL PERFORMANCE CHARACTERISTICS

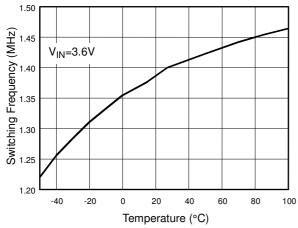


Fig. 3 Switching Frequency vs. Temperature

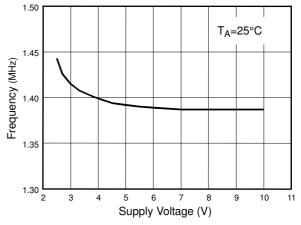


Fig. 4 Frequency vs. Supply Voltage

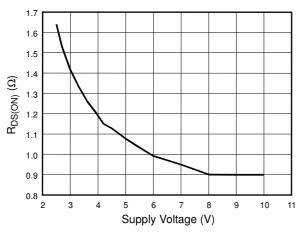


Fig. 5 R_{DSON} vs. Supply Voltage

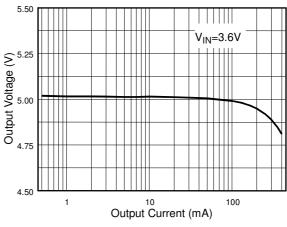


Fig. 6 Load Regulation (L1=10 μ H)

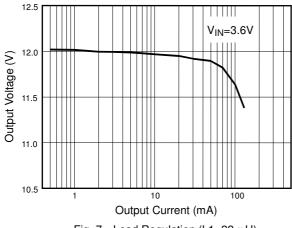


Fig. 7 Load Regulation (L1=22 μ H)

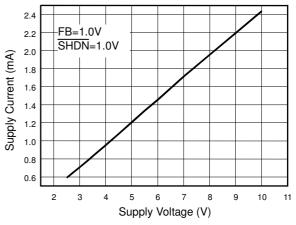
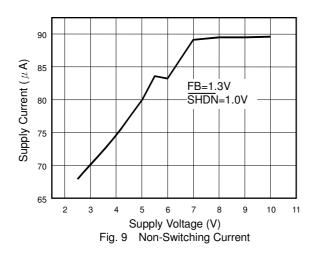
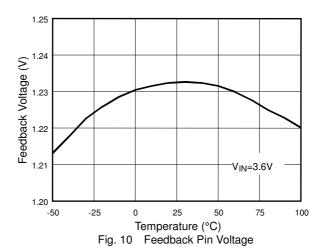


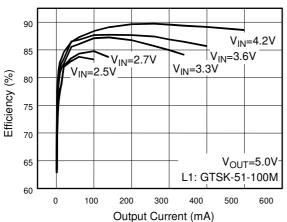
Fig. 8 Switching Current

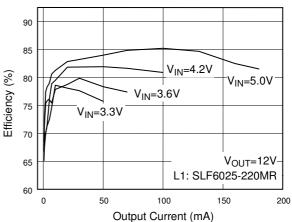


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)









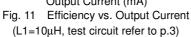
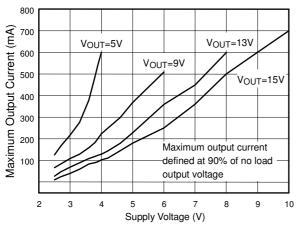


Fig. 12 Efficiency vs. output current (L1=22μH, test circuit refer to p.3)



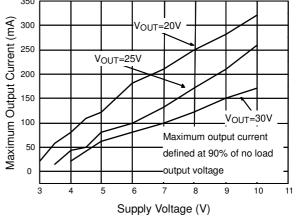
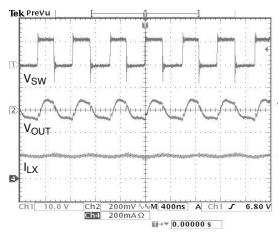


Fig. 13(a) Maximum Output current vs. Supply Voltage (L1: 10μH, test circuit refer to p.3)

Fig. 13(b) Maximum Output Current vs. Supply Voltage (L1:22µH, test circuit refer to p.3)



TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



 $Fig.~14 \quad Operation~Wave~Form\\ (V_{IN}=5V;~V_{OUT}=12V,~L1=22\mu H;~R1=105K;\\ R2=12K;C3=1nF;I_{OUT}=200mA,~test~circuit~refer~to~p.3)$

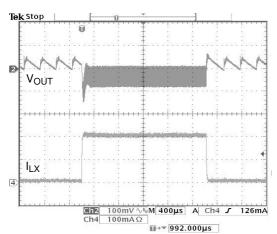


Fig. 16 Load Step Response $(V_{IN}=3.3V; V_{OUT}=5V;L1=10\mu H;I_{OUT}=5mA \text{ to } 200mA, \text{ test circuit refer to p.3})$

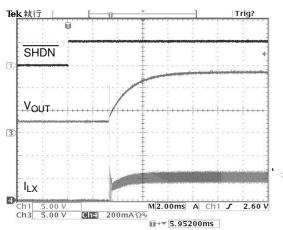


Fig. 18 Start-Up from Shutdown (V_{IN} =3.3V ; V_{OUT} =13V ; R_{LOAD} =300 Ω , test circuit refer to p.3)

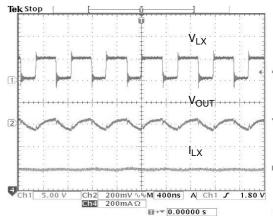


Fig. 15 Operation Wave Form $(V_{\text{IN}}\!\!=\!\!3V;\!V_{\text{OUT}}\!\!=\!\!5V;\!L1\!=\!10\mu\text{H};\!R1\!=\!\!36K;\!R2\!=\!12K;\!$ C3=39pF; $l_{\text{OUT}}\!\!=\!\!200\text{mA}$, test circuit refer to p.3)

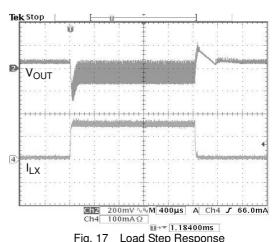
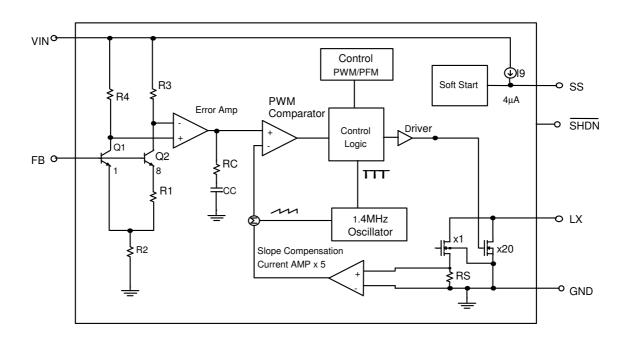


Fig. 17 Load Step Response (V_{IN}=5V; V_{OUT}=12V;L1=22µH;I_{OUT}=5mA to 150mA, test circuit refer to p.3)



BLOCK DIAGRAM



■ PIN DESCRIPTIONS

PIN 1: LX - Power Switching Connection.

Connect LX to inductor and output rectifier. Keep the distance between the components as close to LX as possible.

PIN 2: GND - Ground.

PIN 3: FB - Feedback Input. Connect a resistive voltage-divider from the output to FB to set the output voltage.

PIN 4: SHDN - Shutdown Input. Drive SHDN low to turn off the converter. To automatically start the converter, connect SHDN to IN. Drive

SHDN with a slew rate of 0.1V/μs or greater. Do not leave SHDN unconnected. SHDN draws up to 50μA.

PIN 5: SS - Soft-Start Input. Connect a soft-start capacitor from SS to GND in order to soft-start the converter. Leave SS open to disable the soft-start function.

PIN 6: IN - Internal Bias Voltage Input.

Connect IN to the input voltage source. Bypass IN to GND with a capacitor sitting as close to IN as possible.



APPLICATION INFORMATION

Inductor Selection

A $15\mu H$ inductor is recommended for most AIC1896 applications. Although small size and high efficiency are major concerns, the inductor should have low core losses at 1.4MHz and low DCR (copper wire resistance).

Capacitor Selection

The small size of ceramic capacitors makes them ideal for AlC1896 applications. X5R and X7R types are recommended because they retain their capacitance over wider ranges of voltage and temperature than other types, such as Y5V or Z5U. A $4.7\mu F$ input capacitor and a $1\mu F$ output capacitor are sufficient for most AlC1896 applications.

Diode Selection

Schottky diodes, with their low forward voltage drop and fast reverse recovery, are the ideal choices for AlC1896 applications. The forward voltage drop of a Schottky diode represents the conduction losses in the diode, while the diode capacitance (CT or CD) represents the switching losses. For diode selection, both forward voltage drop and diode capacitance need to be considered. Schottky diodes with higher current ratings usually have lower forward voltage drop and larger diode capacitance, which can cause significant switching losses at the 1.4MHz switching frequency of AlC1896. A Schottky diode rated at 100mA to 200mA is sufficient for most AlC1896 applications.

LED Current Control

LED current is controlled by feedback resistor (R1 in Fig. 1). The feedback reference is 1.23V. The LED current is 1.23V/R1. In order to have

accurate LED current, precision resistors are preferred (1% recommended). The formula for R1 selection is shown below.

 $R1 = 1.23V/I_{LED}$ (1)

Open-Circuit Protection

In the cases of output open circuit, when the LEDs are disconnected from the circuit or the LEDs fail, the feedback voltage will be zero. AIC1896 will then switch to a high duty cycle resulting in a high output voltage, which may cause SW pin voltage to exceed its maximum 30V rating. A zener diode can be used at the output to limit the voltage on SW pin (Fig. 20). The zener voltage should be larger than the maximum forward voltage of the LED string. The current rating of the zener should be larger than 0.1mA.

Dimming Control

There are three different types of dimming control circuits as follows:

1. Using a PWM signal

PWM brightness control provides the widest dimming range by pulsing LEDs on and off at full and zero current, repectively. The change of average LED current depends on the duty cycle of the PWM signal. Typically, a 0.1kHz to 10kHz PWM signal is used. Two applications of PWM dimming with AIC 1896 are shown in Fig 21. One, as fig. 21(a), uses PWM signal to drive SHDN pin directly for dimming control. The other, as fig. 21(b), employs PWM signal going through a resistor to drive FB pin. If the SHDN pin is used, the increase of duty cycle results in LED brightness enhancement. If the FB pin is used, on the contrary, the increase of duty cycle will decrease its brightness. In this application, LEDs



are dimmed by FB pin and turned off completely by $\overline{\rm SHDN}$.

2. Using a DC Voltage

For some applications, the preferred method of a dimming control uses a variable DC voltage to adjust LED current. A dimming control using a DC voltage is shown as Fig. 22. As DC voltage increases, the voltage drop over R2 increases and the voltage drop over R1 decreases.

Cautiously selecting R2 and R3 is essential so that the current from the variable DC source is much smaller than the LED current and much larger than the FB pin bias current. With a VDC ranging from 0V to 5V, the selection of resistors in Fig. 22 results in dimming control of LED current from 20mA to 0mA, respectively.

3. Using a Filtered PWM Signal

Filtered PWM signal can be considered as an adjustable DC voltage. It can be used to replace the variable DC voltage source in dimming control. The circuit is shown in Fig. 23.

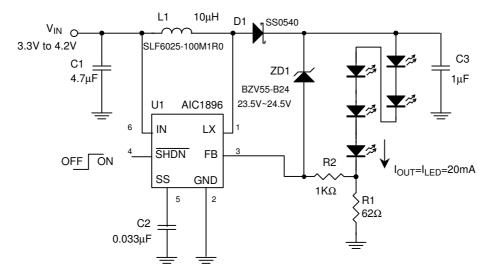


Fig. 19 White LED Driver with Open-Circuit Protection

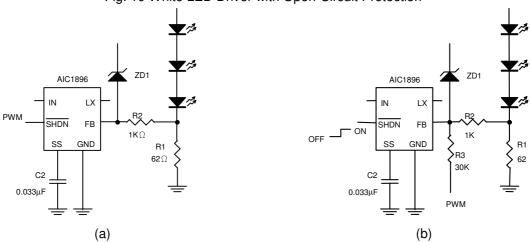


Fig. 20 Dimming Control Using a PWM Signal



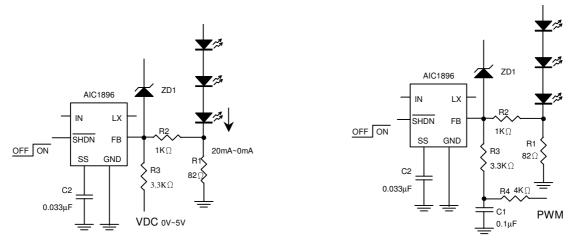


Fig. 21 Dimming Control Using a DC Voltage

Fig. 22 Dimming Control Using a Filtered PWM Signal

APPLICATION EXAMPLES

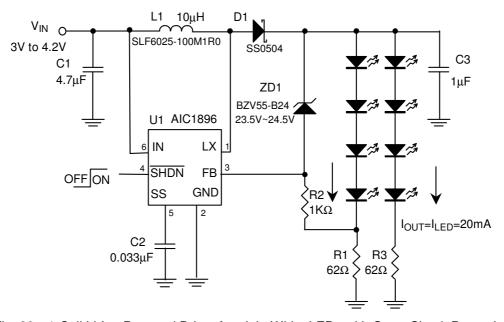


Fig. 23 1-Cell Li-Ion Powered Driver for eight White LEDs with Open-Circuit Protection



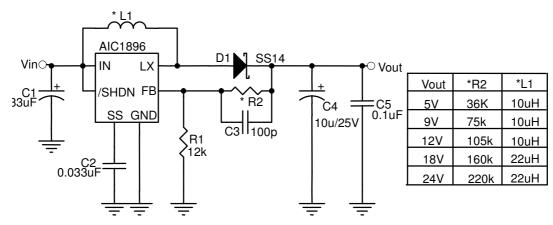


Fig. 24 Typical Step up Application Circuit

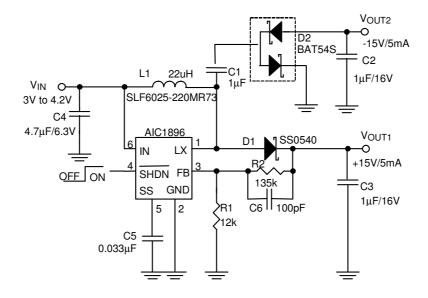


Fig. 25 1-Cell Li-Ion to \pm 15V/5mA Dual Output Converter for LCD Bias

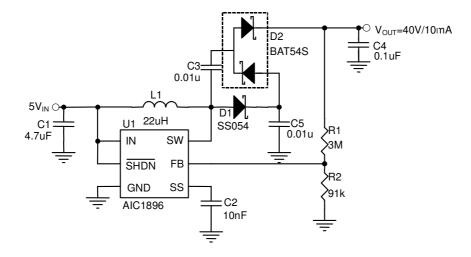


Fig. 26 High 40V Output Voltage for Electrophoretic Display (EPD) Application



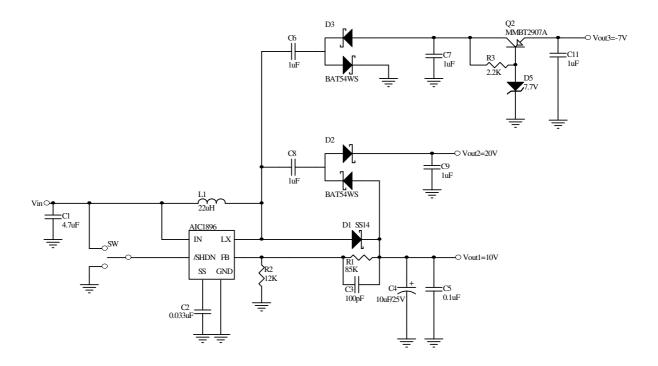
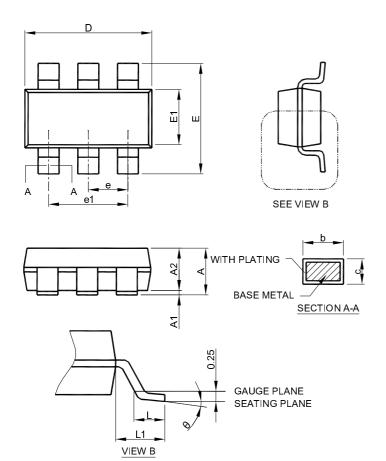


Fig. 27 Three output voltage for LCD



■ PHYSICAL DIMENSIONS (unit: mm)

• TSOT-23-6



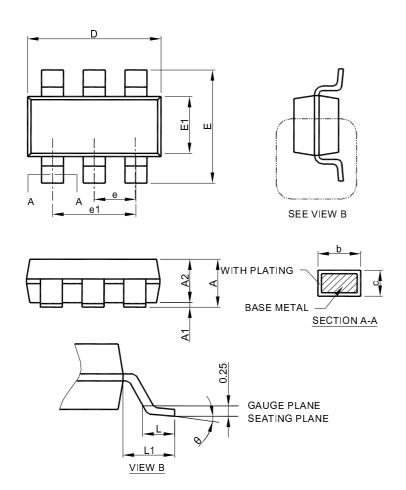
| S Y | TSOT-23-6 MILLIMETERS | | |
|-------------|--------------------------|------|--|
| M B O | | | |
| O L | MIN. | MAX. | |
| Α | - | 1.00 | |
| A1 | 0 | 0.10 | |
| A2 | 0.70 | 0.90 | |
| b | 0.30 | 0.50 | |
| С | 0.08 | 0.22 | |
| D | 2.80 | 3.00 | |
| Е | 2.60 | 3.00 | |
| E1 | 1.50 | 1.70 | |
| е | 0.95 BSC | | |
| e1 | 1.90 BSC | | |
| L | 0.30 | 0.60 | |
| L1 | 0.60 REF | | |
| θ | 0° | 8° | |

Note: 1. Refer to JEDEC MO-193AA.

- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "E1" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



SOT-23-6



| S Y | SOT-23-6 MILLIMETERS | | |
|-------------|-------------------------|------|--|
| М В О | | | |
| O L | MIN. | MAX. | |
| Α | 0.95 | 1.45 | |
| A1 | 0.05 | 0.15 | |
| A2 | 0.90 | 1.30 | |
| b | 0.30 | 0.50 | |
| С | 0.08 | 0.22 | |
| D | 2.80 | 3.00 | |
| Е | 2.60 | 3.00 | |
| E1 | 1.50 | 1.70 | |
| е | 0.95 BSC | | |
| e1 | 1.90 BSC | | |
| L | 0.30 | 0.60 | |
| L1 | 0.42 REF | | |
| θ | 0° | 8° | |

Note: 1. Refer to JEDEC MO-178AB.

- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 10 mil per side.
- 3. Dimension "E1" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

Note:

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